

SURFACE MOUNT RECTIFIER

VOLTAGE RANGE: 50 --- 600 V

CURRENT: 1.0 A

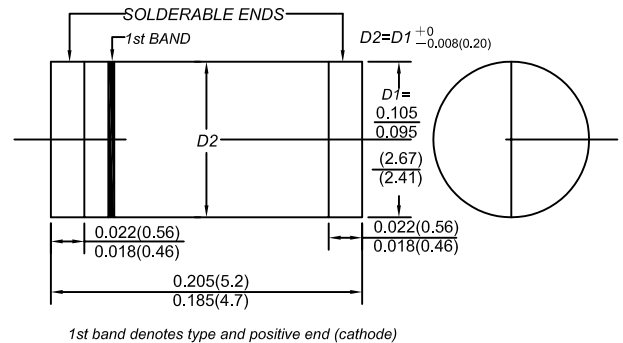
FEATURES

Glass passivated device
Ideal for surface mounted applications
Low leakage
Low forward voltage drop
High current capability
Easily cleaned with Alcohol, Isopropnol
and similar solvents
The plastic material carries U/L
recognition 94V-0

MECHANICAL DATA

Case: JEDEC DO-213AB, molded plastic
Terminals: Solderable per MIL- STD-202,
Method 208
Polarity: Color band denotes cathode
Weight: 0.0046 ounces, 0.116 grams
Mounting position: Any

DO-213AB



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

		SM4933	SM4934	SM4935	SM4936	SM4937	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	V
Maximum average forward rectified current @ $T_A=55$	I_{AV}	1.0					A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	I_{FSM}	30					A
Maximum instantaneous forward voltage @ 1.0A	V_F	1.2					V
Maximum reverse current @ $T_A=25$ at rated DC blocking voltage @ $T_A=125$	I_R	5.0 100					μA
Maximum reverse recovery time (Note1)	t_{rr}	200					ns
Typical junction capacitance (Note2)	C_j	15					pF
Maximum thermal resistance (Note3)	$R_{\theta JL}$	30					/W
Maximum thermal resistance (Note4)	$R_{\theta JA}$	75					/W
Operating junction temperature range	T_j	-55 --- + 150					
Storage temperature range	T_{STG}	-55 --- + 150					

NOTE: 1. Test conditions: $I_F=1.0A$, $V_R=30V$.

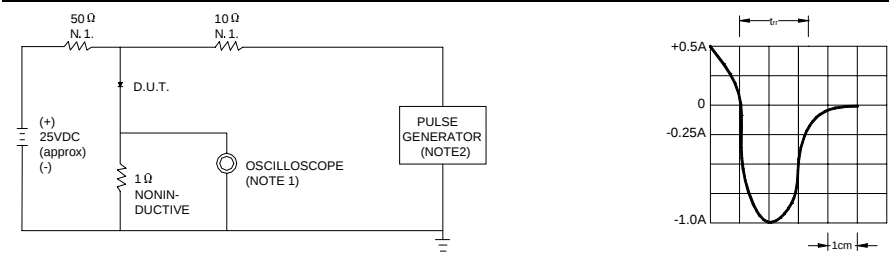
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to terminal 6.0mm² copper pads to each terminal.

4. Thermal resistance junction to ambient 6.0mm² copper pads to each terminal.

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FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES:1.RISE TIME = 7ns MAX.INPUT IMPEDANCE = 1MΩ .22pF.
2.RISE TIME =10ns MAX.SOURCE IMPEDANCE=50 Ω .

SET TIME BASE FOR 80ns/cm

FIG.2 -- TYPICAL FORWARD CHARACTERISTIC

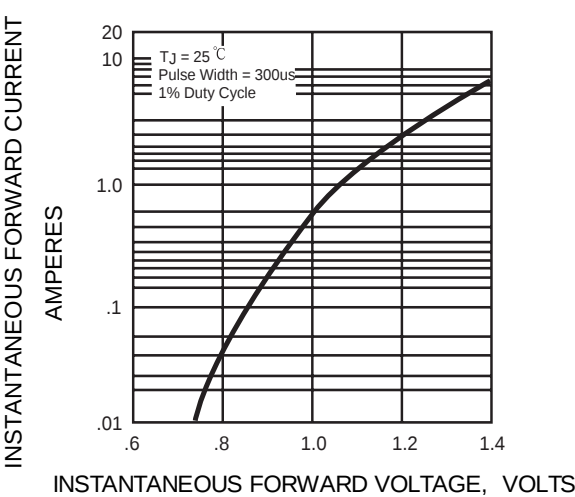


FIG.3 -- FORWARD DERATING CURVE

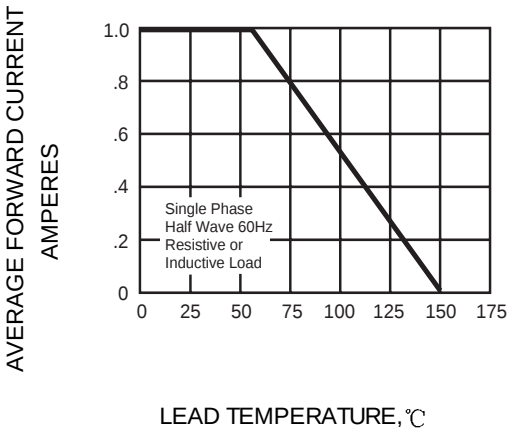


FIG.4 -- TYPICAL JUNCTION CAPACITANCE

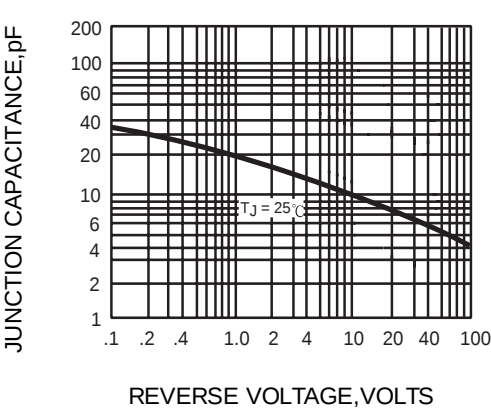


FIG.5 -- PEAK FORWARD SURGE CURRENT

